

NX6411GH

LASER DIODE

R08DS0041EJ0500 Rev.5.00 Jun 07, 2011

1 490 nm InGaAsP MQW-DFB LASER DIODE FOR 2.5 Gb/s FTTH PON APPLICATION

DESCRIPTION

The NX6411GH is a 1 490 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD.

APPLICATION

• 2.5 Gb/s FTTH PON (Fiber To The Home Passive Optical Network)

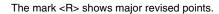
FEATURES

 $\begin{array}{ll} \bullet & \text{Optical output power} & \text{P}_0 = 14.0 \text{ mW} \\ \bullet & \text{Low threshold current} & \text{Ith} = 10 \text{ mA} \\ \bullet & \text{Differential efficiency} & \eta_{\text{d}} = 0.3 \text{ W/A} \\ \bullet & \text{Wide operating temperature range} & \text{Tc} = -40 \text{ to} +85^{\circ}\text{C} \\ \end{array}$

• InGaAs monitor PIN-PD

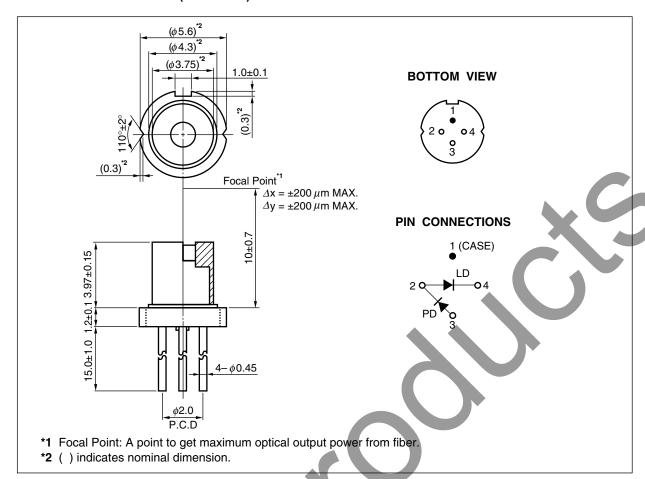
CAN package φ 5.6 mm
 Focal point 10 mm





The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

<R>> PACKAGE DIMENSIONS (UNIT: mm)





ORDERING INFORMATION

Part Number	Package	Pin Connections
NX6411GH	4-pin CAN with aspherical lens cap	2 0 0 4 PD 0 3

Remarks 1. The color of lens cap might be observed differently.

2. The hermetic test will be performed as AQL 1.0%.



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Optical Output Power	Po	20	mW
Forward Current of LD	lF	200	mA
Reverse Voltage of LD	VR	2.0	V
Forward Current of PD	lF	10.0	mA
Reverse Voltage of PD	VR	15	V
Operating Case Temperature	Tc	-40 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
Lead Soldering Temperature	Tsld	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

ELECTRO-OPTICAL CHARACTERISTICS (Tc = -40 to +85°C, unless otherwise specified)

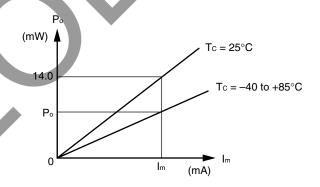
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Optical Output Power	Po	CW		14.0		mW
Operating Current	lop	Po = 14.0 mW			140	mA
Operating Voltage	Vop	Po = 14.0 mW		1.1	1.6	V
Threshold Current	Ith	Tc = 25°C	5	10	15	mA
			3		40	
Differential Efficiency	η d	Po = 14.0 mW	0.10		0.6	W/A
Peak Emission Wavelength	λρ	CW, P _o = 14.0 mW	1 480		1 500	nm
Side Mode Suppression Ratio	SMSR	Po = 14.0 mW	30			dB
Rise Time	tr	lb = lth, 10-90%		0.1	0.2	ns
Fall Time	tf	lb = Ith, 90-10%		0.1	0.2	ns
Monitor Current	lm	V _R = 1.5 V, P _o = 14.0 mW	200	500	1 500	μΑ
Monitor Dark Current	ΙD	V _R = 5 V			100	nA
Tracking Error*1	γ	$I_m = const.$ (@ $P_o = 14.0$ mW, $T_c = 25$ °C)	-1.0		1.0	dB

*1 Tracking Error: γ

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$$\gamma = \left| 10 \log \frac{P_0}{14.0} \right| [dB]$$

REFERENCE

Document Name	Document No.
Opto-Electronics Devices Pamphlet ¹	PX10160E

^{*1} Published by the former NEC Electronics Corporation.



SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

Warning Laser Beam	A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight. • Do not look directly into the laser beam. • Avoid exposure to the laser beam, any reflected or collimated beam.
Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	Do not lick the product or in any way allow it to enter the mouth.



Revision History

NX6411GH Data Sheet

		Description	
Rev.	Date	Page	Summary
_	Mar 2010	_	Previous No. : PL10644EJ04V0DS
5.00	Jun 07, 2011	p.2	Modification of PACKAGE DIMENSIONS
		p.4	ELECTRO-OPTICAL CHARACTERISTICS
			Peak Emission Wavelength: (MIN.) 1 481 -> 1 480, (MAX.) 1 499 -> 1 500
			Monitor Current: (MIN.) 250 -> 200
			Tracking Error: (MIN.) -0.8 -> -1.0, (MAX.) 0.8 -> 1.0



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